## ECE 320 - Homework #3

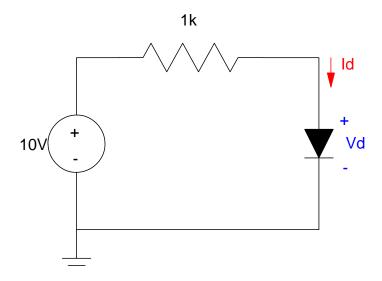
Diode VI Characteristics, Ideal Diode, LEDs. Due Monday, January 29th, 2018

## **Diode VI Characteristics**

Assume the VI characteristics for a diode are:

$$V_d = 0.052 \cdot \ln(10^8 I_d + 1)$$
  $I_d = 10^{-8} \left( \exp\left(\frac{V_d}{0.052}\right) - 1 \right)$ 

- 1) Write the voltage node equations for the following circuit using the nonlinear diode equations (above). Solve these nonlinear equations to find Vd and Id.
- 2) Draw the load-line for this diode circuit. Solve for Vd and Id using load-line analysis.
- 3) Assume an ideal silicon diode. Compute Vd and Id.
- 4) Check your answer in PartSim using a 1004 Fairchild diode.



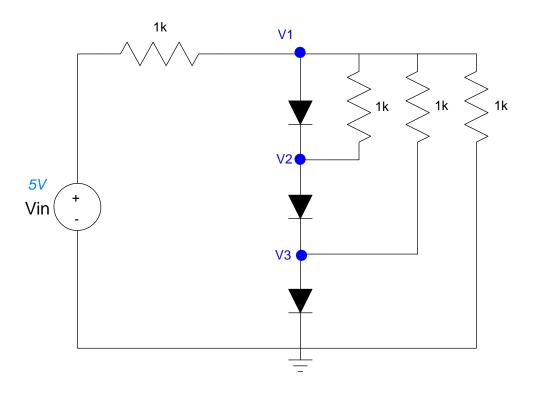
Problem 1-4

Problem 5-8) For the following diode circuit with Vin = +5V

- 5) Write the voltage node equations using the nonlinear model for the diodes.
- 6) Solve for the node voltages using Matlab (or similar program)
- 7) Assume ideal silicon diodes. Solve for V1, V2, V3
- 8) Check your answers in PartSim (or similar program)

## Lab:

9) Build this diode circuit below and check your calculations



Problem 5-9